

Electronic Acknowledgement Receipt

EFS ID:	8561653
Application Number:	10575625
International Application Number:	
Confirmation Number:	4644
Title of Invention:	Group-III nitride semiconductor device
First Named Inventor/Applicant Name:	Hiromitsu Sakai
Customer Number:	23373
Filer:	Abraham Jacob Rosner/Cora Flanagan
Filer Authorized By:	Abraham Jacob Rosner
Attorney Docket Number:	Q78084
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Application Type:	U.S. National Stage under 35 USC 371

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File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/Message Digest	Multi Part/.zip	Pages (if appl.)
1		Q78084_IDS.PDF	141950 e3471b57e1619640fd622e4c3955b92cec 416e3	yes	4

	Multipart Description/PDF files in .zip description								
	Document Description		Start	End					
	Transmittal Letter		1	2					
	Information Disclosure Statement (IDS) Filed (SB/08)		3	4					
Warnings:									
Information:									
2	Foreign Reference	EP_1_160_882.PDF	2604628 08aab71f17eb5a5ea0581d398e37ea6b3fd 65c39	no	16				
Warnings:									
Information:									
3	NPL Documents	TAKEUCHI_ET_AL_Improvement_of_far-field_pattern_ETC.PDF	711227 a97829b9ec81f9ee7ec739368951a767302 2bf5e	no	3				
Warnings:									
Information:									
4	NPL Documents	ADELMANN_ET_AL_Atomic-layer_epitaxy_of_GaN_quantum_wells_ETC.PDF	942184 70aa9ba4f4bb6bd7f8f02dd89460081b9c3 bf95d	no	3				
Warnings:									
Information:									
5	NPL Documents	MIYAMURA_ET_AL_Stranski-Krastanow_growth_of_GaN_quantum_dots_ETC.PDF	685343 e126aa94d89da2670a196db39b559d7d96 93fe51	no	4				
Warnings:									
Information:									
6	NPL Documents	HUANG_ET_AL_Defect_reduction_with_quantum_dots_in_GaN_ETC.PDF	946272 66e28a1cace053d91e654a04596eac147c4 b2914	no	3				
Warnings:									
Information:									
7	NPL Documents	Supplemental_European_Search_Report_EP04792622.PDF	676951 1464e9154475f3614f02da37647efd013642 23b3	no	5				
Warnings:									
Information:									
Total Files Size (in bytes):				6708555					

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New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.